Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material: Metal

Overall Length:

Between 0.140 inches and 0.260 inches

Terminal Length:

0.500 inches

Overall Diameter:

Between 0.335 inches and 0.370 inches

Component Name And Quantity:

2 transistor

Mounting Method:

Terminal

Terminal Circle Diameter:

0.200 inches

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

-15.0 collector to emitter voltage/static/base open all transistor and -20.0 collector to base voltage, dc all transistor and -5.0 emitter to base, rms all transistor

Current Rating Per Characteristic:

50.00 milliamperes source cutoff current all transistor

Power Rating Per Characteristic:

300.0 milliwatts small-signal input power, common-collector preset all transistor

Special Features:

All transistor junction pattern arrangement: pnp

Terminal Type And Quantity:

6 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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